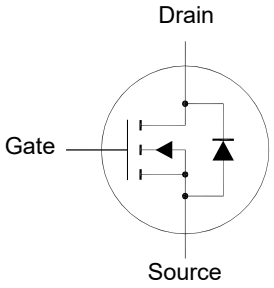
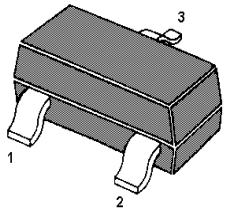
MKA10N560L

N-Channel Enhancement Mode MOSFET

Features

• Surface-mounted package





1. Gate 2. Source 3. Drain
SOT-23 Plastic Package

Applications

• Portable appliances

• Battery management

Absolute Maximum Ratings(at T_a = 25℃ unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	100	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	1	A
Peak Drain Current, Pulsed tp ≤ 10 μs	I_{DM}	4	A
Power Dissipation [1)]	P_D	1	W
Operating Junction Temperature	T_J	150	℃
Storage Temperature Range	T_{stg}	- 55 to + 150	℃

Thermal Characteristics

Parameter	Symbol	Max.	Unit
Thermal Resistance from Junction to Ambient [1)]	$R_{\theta JA}$	125	℃/W

[1)] Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate in still air, t < 10 s.

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Characteristics at T_a = 25℃ unless otherwise specified

Parameter	Symbol	Min.	Typ.	Max.	Unit
STATIC PARAMETERS					
Drain-Source Breakdown Voltage at I_D = 1 mA	BV_{DSS}	100	-	-	V
Drain-Source Leakage Current at V_{DS} = 100 V	I_{DSS}	-	-	1	µA
Gate Leakage Current at V_{GS} = ± 20 V	I_{GSS}	-	-	± 100	nA
Gate-Source Threshold Voltage at V_{DS} = V_{GS}, I_D = 250 µA	$V_{GS(th)}$	1	-	2.5	V
Drain-Source On-State Resistance at V_{GS} = 10 V, I_D = 1 A at V_{GS} = 4.5 V, I_D = 1 A at V_{GS} = 4 V, I_D = 1 A	$R_{DS(on)}$	- - -	- - -	520 560 580	mΩ
DYNAMIC PARAMETERS					
Forward Transconductance at V_{DS} = 5 V, I_D = 1 A	g_{Fs}	-	4.1	-	S
Gate resistance at V_{DS} = 0 V, V_{GS} = 0 V, f = 1 MHz	R_g	-	0.9	-	Ω
Input Capacitance at V_{GS} = 0 V, V_{DS} = 50 V, f = 1 MHz	C_{iss}	-	454	-	pF
Output Capacitance at V_{GS} = 0 V, V_{DS} = 50 V, f = 1 MHz	C_{oss}	-	17	-	pF
Reverse Transfer Capacitance at V_{GS} = 0 V, V_{DS} = 50 V, f = 1 MHz	C_{rss}	-	13	-	pF
Gate charge total at V_{DS} = 50 V, V_{GS} = 10 V, I_D = 1 A at V_{DS} = 50 V, V_{GS} = 4.5 V, I_D = 1 A	Q_g	- -	8.4 3.9	- -	nC
Gate-Source Charge at V_{DS} = 50 V, V_{GS} = 10 V, I_D = 1 A	Q_{gs}	-	1.9	-	nC
Gate-Drain Charge at V_{DS} = 50 V, V_{GS} = 10 V, I_D = 1 A	Q_{gd}	-	1.1	-	nC
Turn-On Delay Time at V_{DS} = 50 V, V_{GS} = 10 V, I_D = 1 A, R_g = 3.3 Ω	$t_{d(on)}$	-	9.5	-	nS
Turn-On Rise Time at V_{DS} = 50 V, V_{GS} = 10 V, I_D = 1 A, R_g = 3.3 Ω	t_r	-	4	-	nS
Turn-Off Delay Time at V_{DS} = 50 V, V_{GS} = 10 V, I_D = 1 A, R_g = 3.3 Ω	$t_{d(off)}$	-	8	-	nS
Turn-Off Fall Time at V_{DS} = 50 V, V_{GS} = 10 V, I_D = 1 A, R_g = 3.3 Ω	t_f	-	13	-	nS
Body-Diode PARAMETERS					
Drain-Source Diode Forward Voltage at I_S = 1 A, V_{GS} = 0 V	V_{SD}	-	-	1.2	V
Body-Diode Continuous Current	I_S	-	-	1	A
Body Diode Reverse Recovery Time at I_S = 1 A, di/dt = 100 A / µs	t_{rr}	-	17	-	nS
Body Diode Reverse Recovery Charge at I_S = 1 A, di/dt = 100 A / µs	Q_{rr}	-	14.5	-	nC

Electrical Characteristics Curves

Fig. 1 Typical Output Characteristics

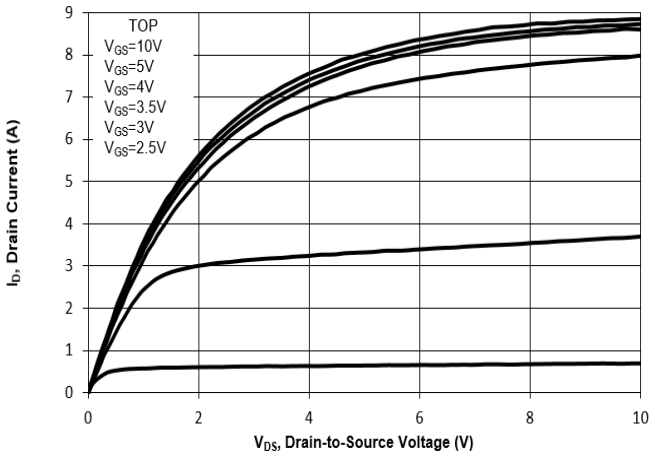


Fig. 2 Typical Transfer Characteristics

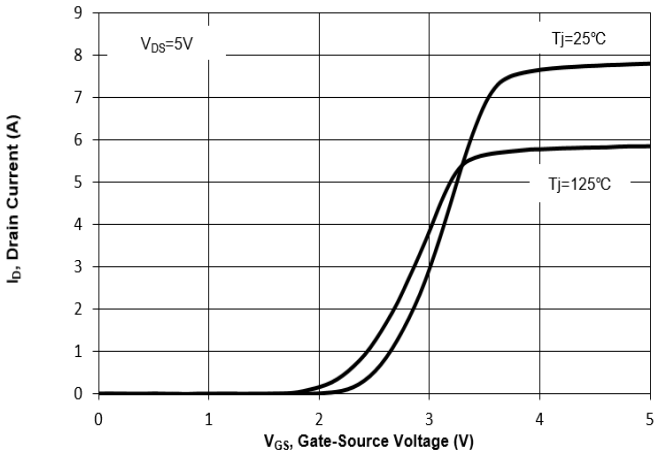


Fig. 3 On-Resistance vs. Drain Current

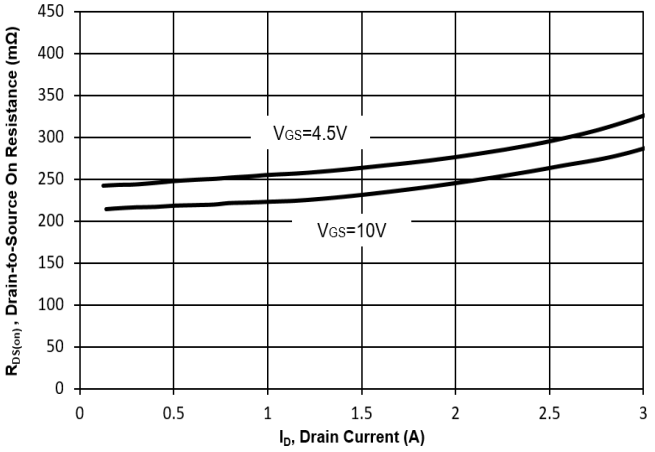


Fig. 4 On-Resistance vs. Gate-Source Voltage

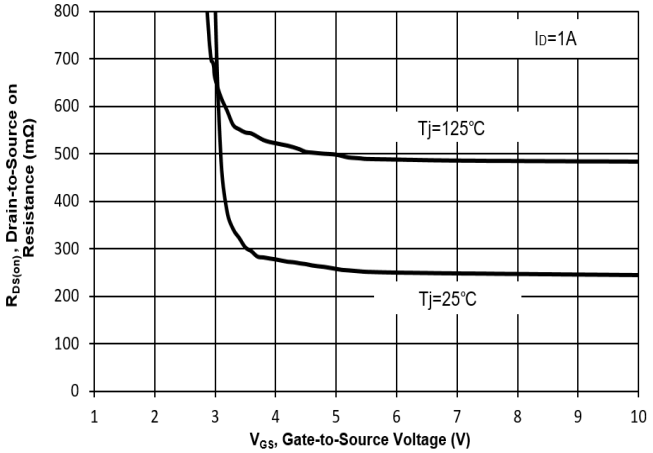


Fig. 5 On-Resistance vs.T_j

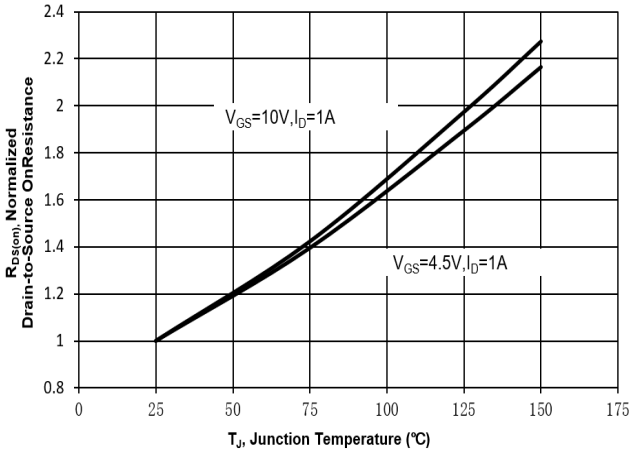
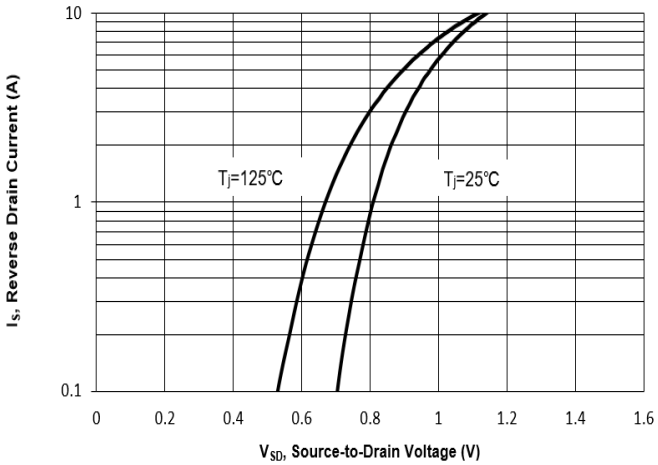


Fig. 6 Typical Body-Diode Forward Characteristics



Electrical Characteristics Curves

Fig. 7 Typical Junction Capacitance

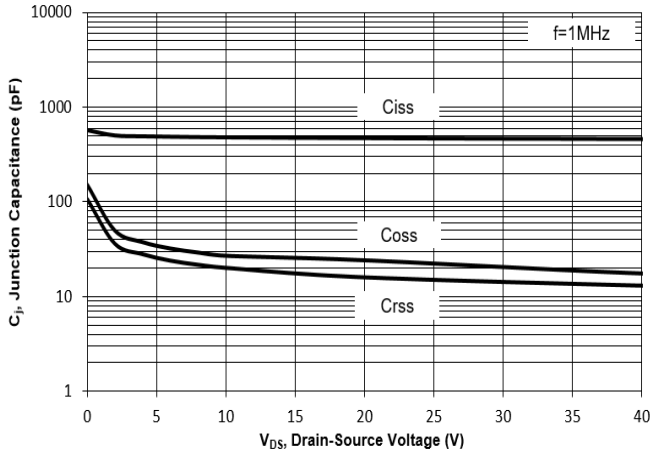


Fig. 8 Drain-Source Leakage Current vs. T_j

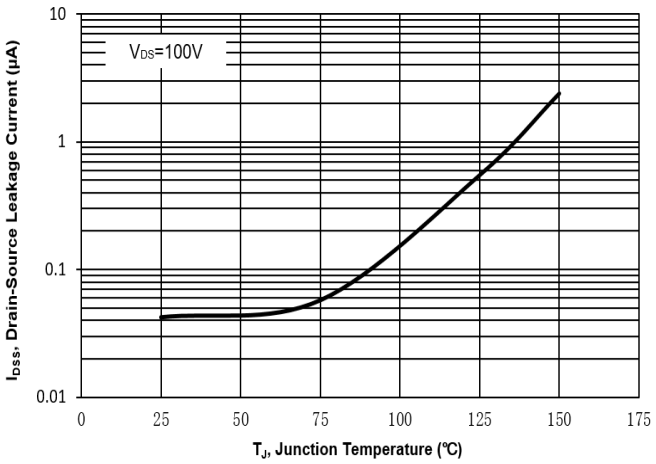


Fig. 9 $V_{(BR)DSS}$ vs. Junction Temperature

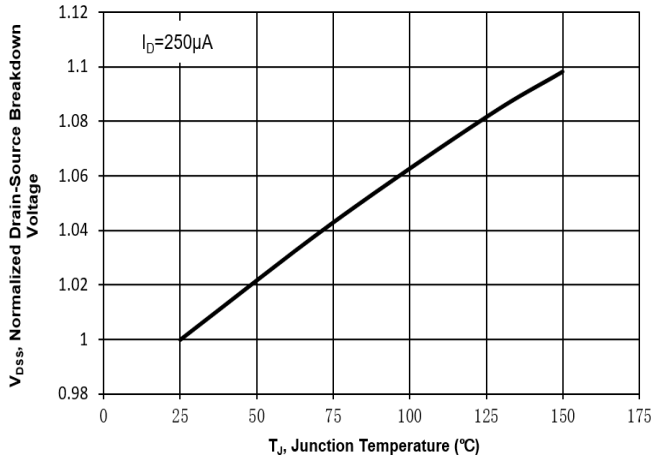


Fig. 10 Gate Threshold Variation vs. T_j

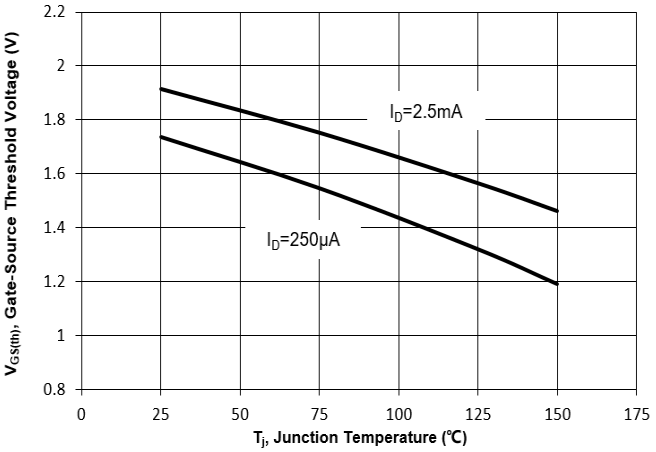
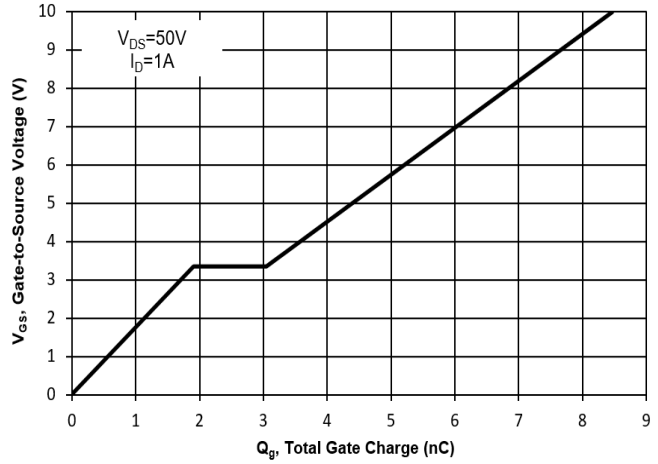


Fig. 11 Gate Charge



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Test Circuits

Fig.1-1 Switching times test circuit

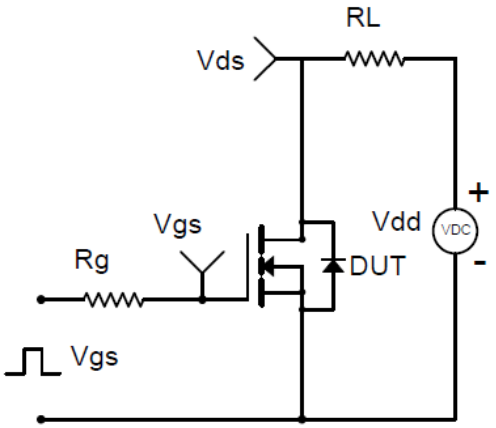


Fig.1-2 Switching Waveform

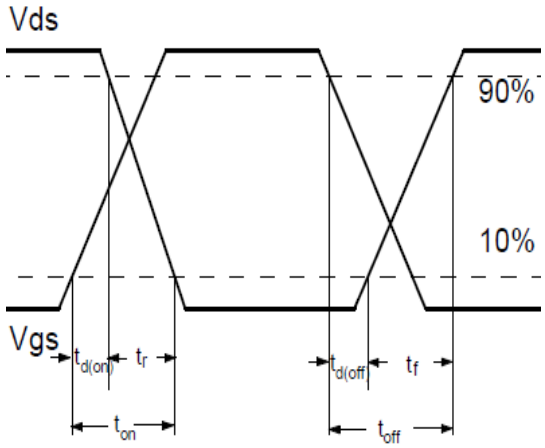


Fig.2-1 Gate charge test circuit

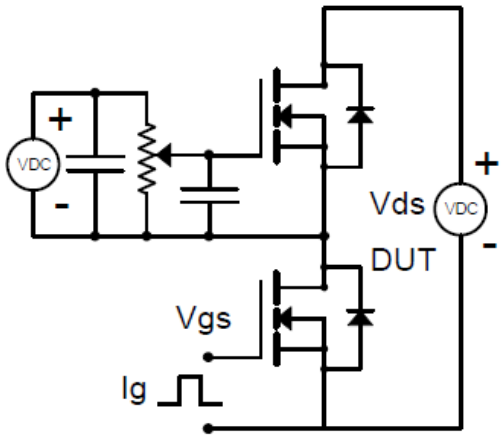
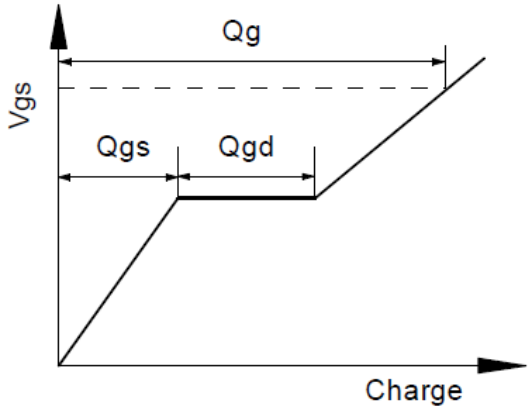
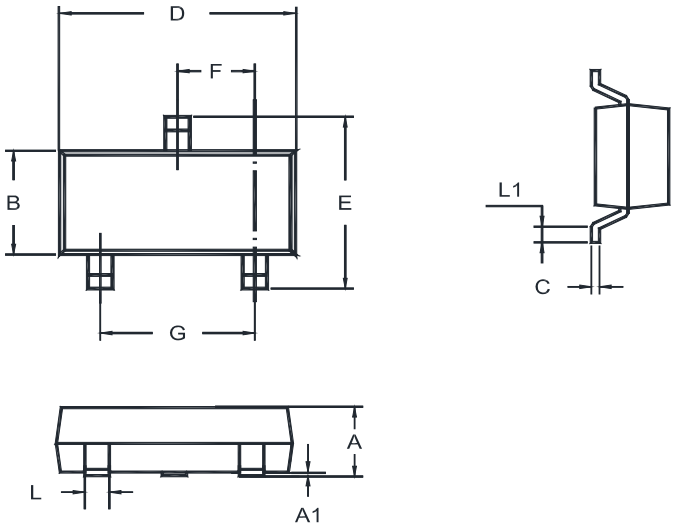


Fig.2-2 Gate charge waveform

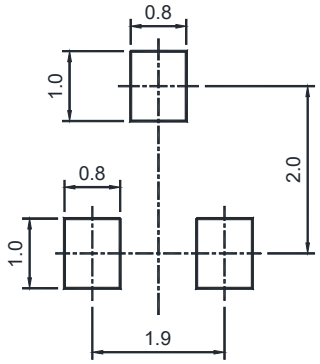


Package Outline (Dimensions in mm) SOT-23



Unit	A	A1	B	C	D	E	F	G	L	L1
mm	1.20 0.89	0.100 0.013	1.40 1.20	0.19 0.08	3.04 2.80	2.6 2.2	1.02 0.89	2.04 1.78	0.51 0.37	0.2 MIN

Recommended Soldering Footprint

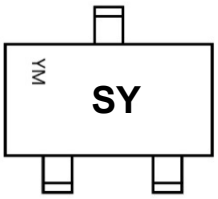


Packing information

Package	Tape Width (mm)	Pitch		Reel Size		Per Reel Packing Quantity
		mm	inch	mm	inch	
SOT-23	8	4 ± 0.1	0.157 ± 0.004	178	7	3,000

Marking information

" SY " = Part No.
" YM " = Date Code Marking
" Y " = Year
" M " = Month
Font type: Arial



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